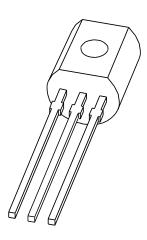
DISCRETE SEMICONDUCTORS

DATA SHEET



PH5416 PNP high-voltage transistor

Product specification Supersedes data of September 1994 File under Discrete Semiconductors, SC04 1997 Apr 22





PNP high-voltage transistor

PH5416

FEATURES

- High current (max. 1 A)
- High voltage (max. 300 V).

APPLICATIONS

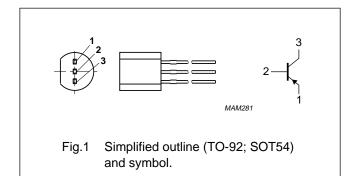
• Telephony applications.

DESCRIPTION

PNP high-voltage transistor in a TO-92; SOT54 plastic package.

PINNING

PIN	DESCRIPTION	
1	emitter	
2	base	
3	collector	



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-350	V
V _{CEO}	collector-emitter voltage	open base	_	-300	V
I _{CM}	peak collector current		_	-1	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	500	mW
h _{FE}	DC current gain	$I_C = -50 \text{ mA}; V_{CE} = -10 \text{ V}$	30	120	
f _T	transition frequency	$I_C = -10 \text{ mA}; V_{CE} = -10 \text{ V}; f = 100 \text{ MHz}$	15	_	MHz

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-350	V
V _{CEO}	collector-emitter voltage	open base	_	-300	V
V _{EBO}	emitter-base voltage	open collector	_	-6	V
I _C	collector current (DC)		_	-1	Α
I _{CM}	peak collector current		_	-1	Α
I _{BM}	peak base current		_	-500	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	500	mW
T _{stg}	storage temperature		-65	150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = -280 V	_	-100	nA
I _{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = -6 V$	_	-100	nA
h _{FE}	DC current gain	$I_C = -50 \text{ mA}; V_{CE} = -10 \text{ V}$	30	120	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	_	-800	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	_	-1	V
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = -10 \text{ V}$; $f = 1 \text{ MHz}$	_	15	pF
C _e	emitter capacitance	$I_C = I_c = 0$; $V_{EB} = -5 \text{ V}$; $f = 1 \text{ MHz}$	_	75	pF
f _T	transition frequency	$I_C = -10 \text{ mA}; V_{CE} = -10 \text{ V};$ f = 100 MHz	15	_	MHz

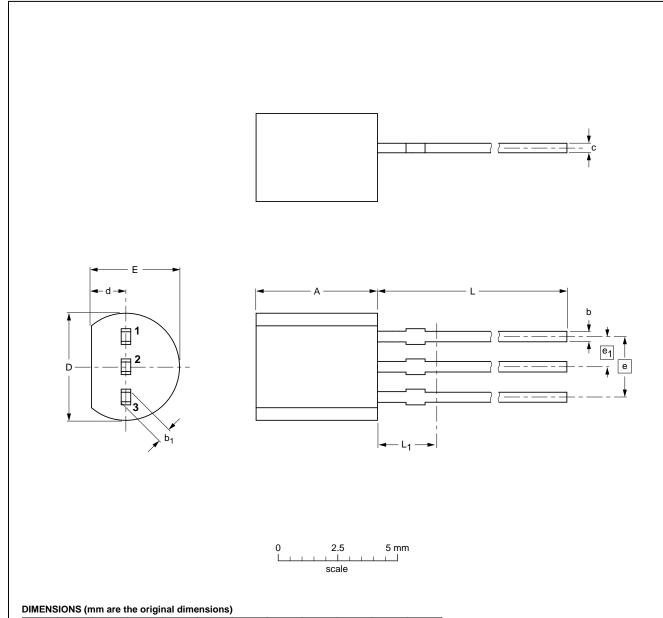
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	Α	b	b ₁	U	D	d	E	е	e ₁	L.	L ₁ ⁽¹⁾
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE REFERENCES				EUROPEAN	ISSUE DATE	
	VERSION	IEC	JEDEC	EIAJ	PROJECTION ISSUE DA	
	SOT54		TO-92	SC-43		97-02-28

PNP high-voltage transistor

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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NOTES

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NOTES

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